

# Ultra-linear Mixer with Integrated IF Amp and LO Buffer

## Description

CMY212 is a general purpose down-converter device designed for multiple applications such as cellular and PCS mobile phones, ISM receivers. bands. GPS L-band satellite terminals, WLAN and pagers. Due to its excellent intermodulation characteristics and gain. its high conversion CMY212 is particularly CDMA suited for receiver applications.

The device combines an ultra-linear mixer with LO - driver and a single stage IF-amplifier in a very small SCT598 package. The mixer section of CMY212 combines low conversion losses and excellent intermodulation characteristics with low requirements of LO and DC-power. The internal level controlled LO-Buffer enables a good performance over a wide LO level range. The input and output matching of the IF amplifier can be adapted externally within a frequency range from 45 to 250 MHz.

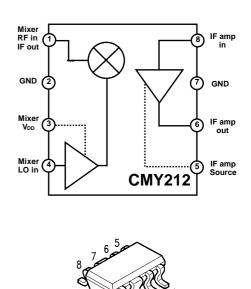
## Features

- Typical overall performance at cellular frequencies (for P<sub>LO</sub> = -4dBm operation conditions: 3V, 11 mA; f<sub>RF</sub> = 881 MHz;
  - f<sub>LO</sub> = 966 MHz):
    - o Gain 10 dB
    - o Input IP3 9 dBm
    - o Noise figure 8 dB
- RF-frequency range 0.5 2.5 GHz
- Operating voltage range: 2.6 to 5V
- Small SCT598 plastic package

# Applications

- Down Converter for Multiple Wireless Applications
- Cellular and PCS
   Mobile Phones
- Particularly Suited for CDMA Receivers
- ISM and WLAN
   Receivers
- GPS Receivers

### Package Outline and Pin Configuration, SCT598



VPW05982

For additional information and latest specifications, see our website: <u>www.triquint.com</u> Revision C. September 1, 000

# **CMY212** Datasheet

### Maximum Ratings

Parameter	Port	Symbol	Value		Unit
			min	max	
Supply Voltage	3,6	V <sub>DD</sub>	0	5	V
DC-Voltage at LO Input	4	V <sub>6</sub>	-3	0,5	V
DC-Voltage at Mixer RF-IF Port	1	V <sub>8</sub>	- 0,5	+ 0,5	V
Power into Mixer RF Port	1	$P_{RF}$		10	dBm
Power into LO Input	4	$P_{in,LO}$	-10	10	dBm
Channel Temperature		$T_{Ch}$		150	°C
Operating Temperature		$T_{op}$	-30	85	°C
Storage Temperature		T <sub>stg</sub>	-55	150	°C
Thermal Resistance*					
Channel to Soldering Point (GND)		$R_{thChS}$	260		K/W



# **CMY212** Datasheet

### **Electrical Characteristics**

Parameter,	Comment		typ	max	Unit
RF - frequency range	external match	0.5	-	2.5	GHz
LO - Frequency range	external match	0.5	-	2.5	GHz
IF Frequency range	external match	45		250	MHz

#### Typical performance at cellular frequencies\*:

 $T_a = 25^{\circ}C$ ;  $V_{DD}= 3V$ ,  $f_{RF} = 881MHz$ ;  $f_{LO} = 966MHz$ ;  $P_{LO} = -4dBm$ ;  $f_{IF} = 85MHz$ ,  $Z_s = Z_L = 50$  Ohm; unless otherwise specified

Parameter, Test Conditions	Symbol	Min	typ	max	Unit
Total operating Current (Mixer + IF amplifier)	I <sub>op</sub>	-	11	-	mA
Conversion Gain	G <sub>c</sub>	-	10	-	dB
SSB Noise Figure	F <sub>ssb</sub>	-	8	-	dB
RF Input -/ IF Output return loss (external matching required)	RFIrl / IFOrl	-	10	-	dB
3rd Order Input Intercept Point	IIP3	-	10	-	dBm

### Test conditions at PCS frequencies:

 $T_a = 25$ °C;  $V_{DD}= 3V$ ,  $f_{RF} = 1960$ MHz;  $f_{LO} = 1750$ MHz;  $P_{LO} = -4$ dBm;  $f_{IF} = 210$ MHz,  $Z_s = Z_L = 50$  Ohm; unless otherwise specified

Parameter, Test Conditions	Symbol	Min	Тур	max	Unit
Total operating Current (Mixer + IF amplifier)	I <sub>op</sub>	-	12	14	mA
Conversion Gain	G <sub>c</sub>	8.5	9.5	-	dB
SSB Noise Figure	F <sub>ssb</sub>	-	8.5	-	dB
RF Input -/ IF output return loss (external matching required)	RFIrl / IFOrl	-	10	-	dB
3rd Order Input Intercept Point	IIP3	10	11.5	-	dBm

\* IMPORTANT NOTE:

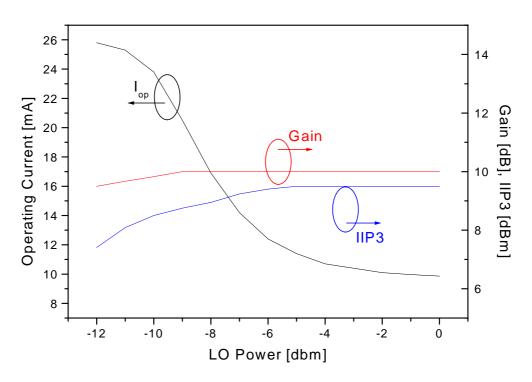
During production, the RF performance at PCS frequencies is screened. The passed devices also achieve the specified RF performance at cellular frequencies.



### **Electrical Characteristics (cont)**

#### Typical device behavior at cellular frequencies:

 $T_a = 25$ °C;  $V_{DD}= 3V$ ,  $f_{RF} = 881$ MHz;  $f_{LO} = 966$ MHz;  $f_{IF} = 85$ MHz;  $Z_s= Z_L = 50$  Ohm; unless otherwise specified

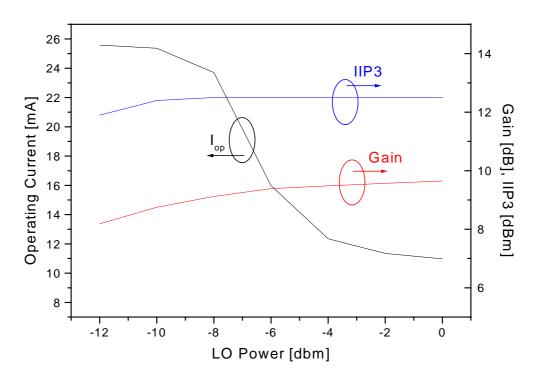


#### Typical device behavior at PCS frequencies:

 $T_a = 25^{\circ}C$ ;  $V_{DD}= 3V$ ,  $f_{RF} = 1960MHz$ ;  $f_{LO} = 1750MHz$ ;  $f_{IF} = 210MHz$ ;  $Z_s= Z_L = 50$  Ohm; unless otherwise specified

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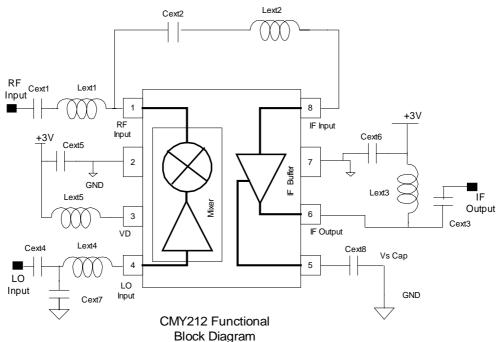
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# Applications Information

Test Circuit:



#### External components for cellular frequencies

 $f_{\rm RF} = 875 \text{MHz}; f_{\rm LO} = 960 \text{MHz}; f_{\rm IF} = 85 \text{MHz}$ 

Capacitors	(Murata 0402)	Inductors	(Toko)
Cext1	2 pF	Lext1	18 nH <i>LL1005</i>
Cext2	1 nF	Lext2	270 nH <i>LL160</i> 8
Cext3	20 pF	Lext3	220 nH <i>LL160</i> 8
Cext4	100 pF	Lext4	12 nH <i>LL1005</i>
Cext5	1 nF	Lext5	15 nH <i>LL1005</i>
Cext6	1 nF		
Cext7	3.3 pF		
Cext8	100 nF	Lext8	22 nH <i>LL1005</i>

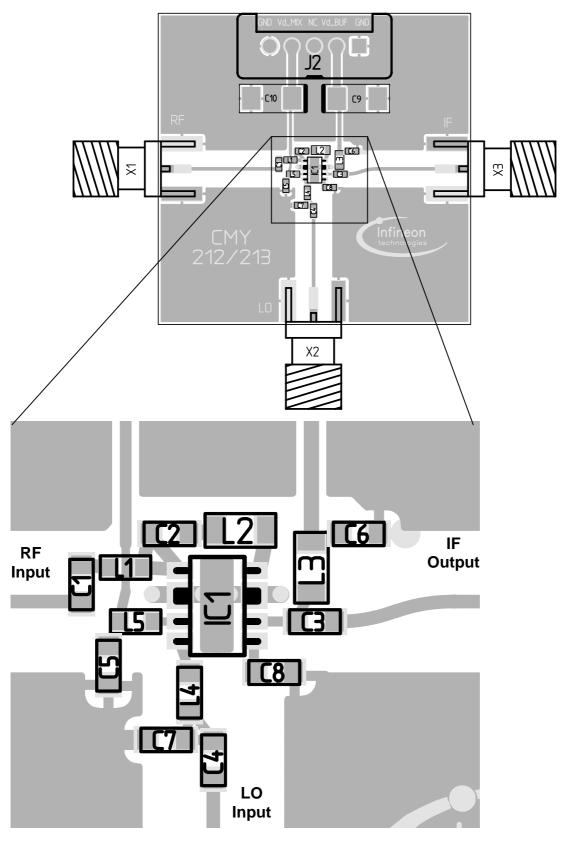
### **External components for PCS frequencies**

 $f_{\rm RF} = 1960 \text{MHz}; f_{\rm LO} = 1750 \text{MHz}; f_{\rm IF} = 210 \text{MHz}$ 

Capacitors	(Murata 0402)	Inductors	(Toko)
Cext1	1 pF	Lext1	5.6 nH <i>LL1005</i>
Cext2	1 nF	Lext2	68 nH <i>LL1608</i>
Cext3	8 pF	Lext3	68 nH <i>LL1608</i>
Cext4	22 pF	Lext4	4.7 nH <i>LL1005</i>
Cext5	1 nF	Lext5	4.7 nH <i>LL1005</i>
Cext6	1 nF		
Cext7	3 pF		
Cext8	100 nF		

## Applications Information (cont)

PCB Layout: Size: 35 x 35 mm<sup>2</sup>



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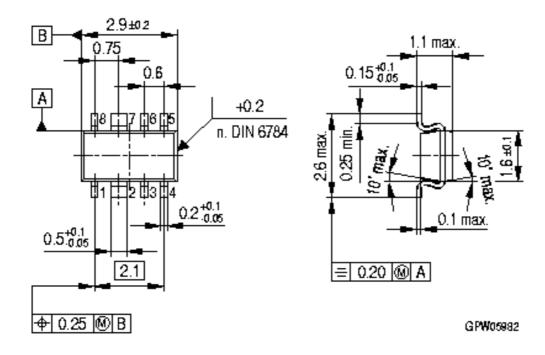
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### General description and notes

CMY212 is a general purpose down-converter device designed for multiple applications such as cellular and PCS mobile phones, ISM bands, GPS receivers, L-band satellite terminals, WLAN and pagers. Due to its excellent intermodulation characteristics and its high conversion gain, CMY212 is particularly suited for CDMA receiver applications.

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### Semiconductor Device Outline SCT598-8-1





### **Ordering Information**

Туре	Marking	Ordering code (tape and reel)	Package <sup>1)</sup>
CMY212	212	CMY212	SCT598-8-1

### Additional Information

This part is compliant with RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment).

The part is rated Moisture Sensitivity Level 1 at 260°C per JEDEC standard IPC/JEDEC J-STD-020.

ESD: Electrostatic discharge sensitive device. Observe handling Precautions.

For latest specifications, additional product information, worldwide sales and distribution locations, and information about TriQuint:

 Web:
 www.triquint.com
 Tel: (503) 615-9000

 Email:
 info\_wireless@tqs.com
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